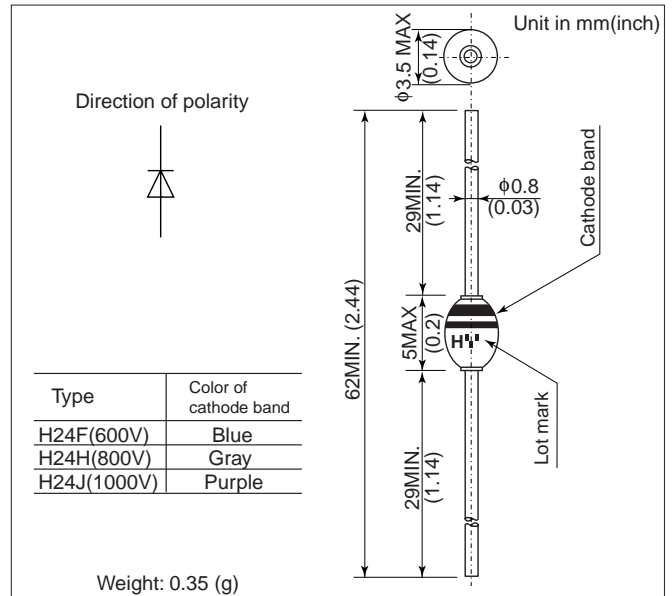


H24

FEATURES

- Transient surge voltage protection.
- Diffused-junction. Glass passivated and encapsulated.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

Items	Type		H24F	H24H	H24J
Repetitive Peak Reverse Voltage	V _{RRM}	V	600	800	1000
Peak Reverse Power	P _{RM}	kW	1 (Ta = 25° C,Pulse duration 20μs Non-repetitive)		
Average Forward Current	I _{F(AV)}	A	1.0 (Single-phase half sine wave 180° conduction Lead length = 10mm)		
Surge(Non-Repetitive) Forward Current	I _{FSM}	A	45(Without PIV, 10ms conduction, T _J max start)		
I ² t Limit Value	I ² t	A ² s	8(Time = 2 ~ 10ms, I = RMS value)		
Operating Junction Temperature	T _J	°C	175	165	
Storage Temperature	T _{stg}	°C	-65 ~ +175		

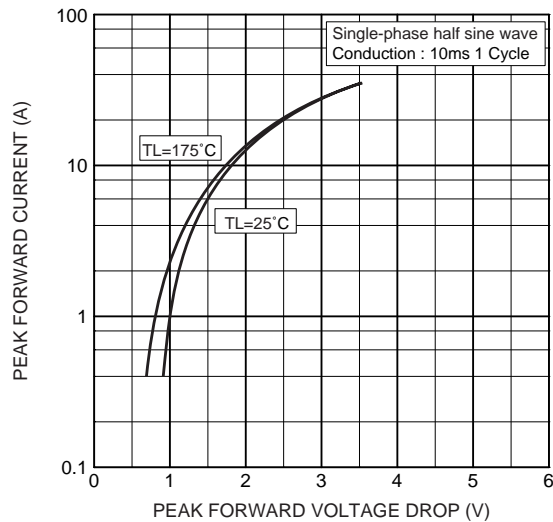
Notes (1) Lead mounting : Lead temperature 300°C max. to 3.2mm from body for 5sec. max..

(2) Mechanical strength : Bending 90°×2 cycles or 180°×1 cycle, Tensile 2kg, Twist 90°×1 cycle.

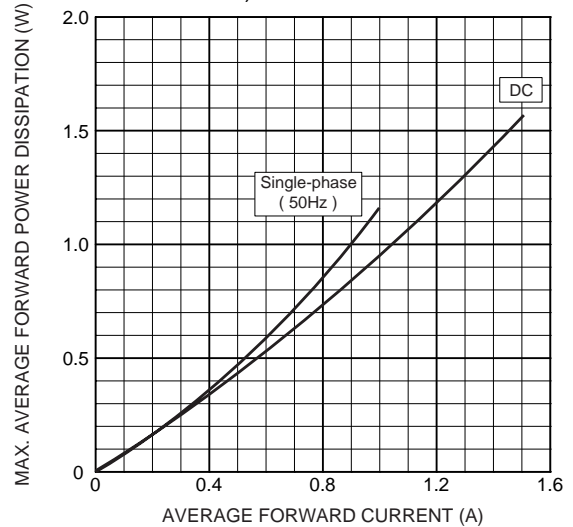
CHARACTERISTICS($T_L=25^\circ\text{C}$)

Items	Symbols	Units	Min.	Typ.	Max.	Test Conditions
Peak Reverse Current	I_{RRM}	μA	—	—	5	All class, Rated V_{RRM}
Peak Forward Voltage	V_{FM}	V	—	—	1.0	$I_{FM}=1.0\text{A}$, Single-phase half sine wave 1 cycle
Reverse Recovery Time	t_{rr}	μs	—	3.0	—	$I_F=2\text{mA}$, $V_R=-15\text{V}$
Avalanche Voltage	V_{AVL}	V	750	—	—	$I_{RM}=1.0\text{mA}$, Single-phase half sine wave 1 pps, Time $\leq 5\text{s}$
			1000	—	—	
			1250	—	—	
Steady State Thermal Impedance	$R_{th(j-a)}$	$^\circ\text{C/W}$	—	—	80	Lead length = 10 mm
	$R_{th(j-l)}$				50	

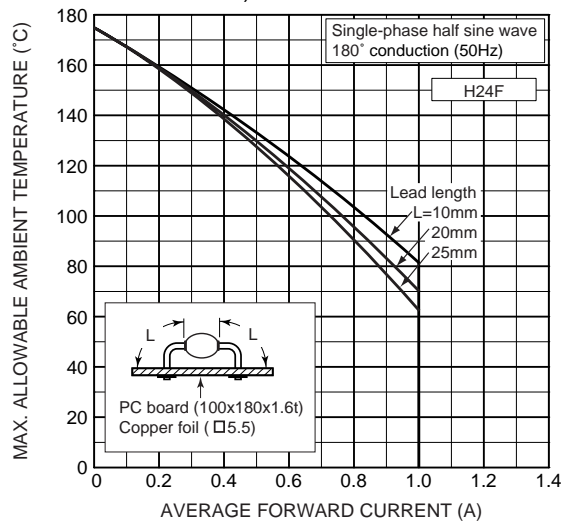
Forward characteristics



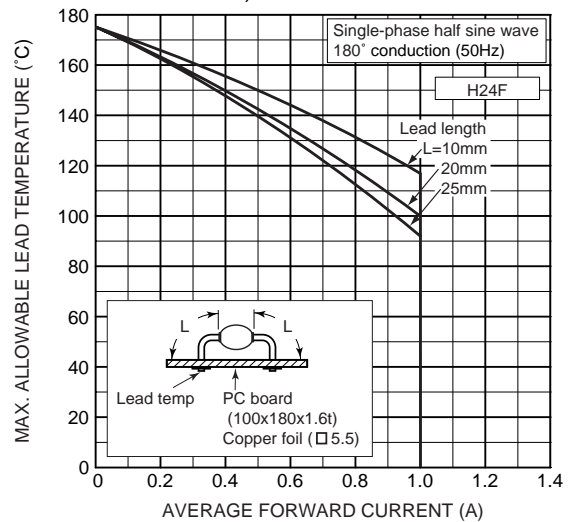
Max. average forward power dissipation (Resistive or inductive load)



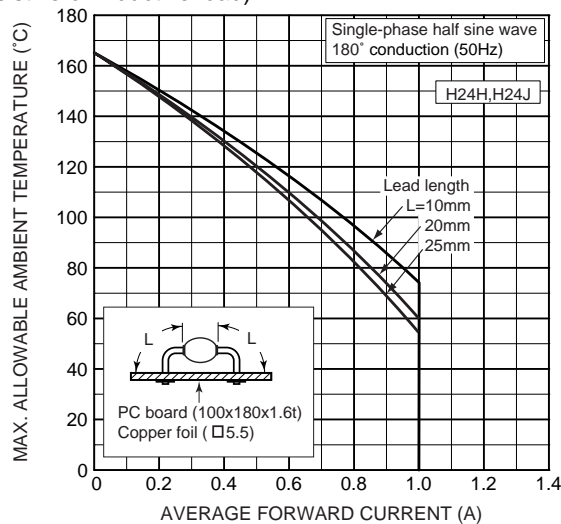
Max. allowable ambient temperature (Resistive or inductive load)



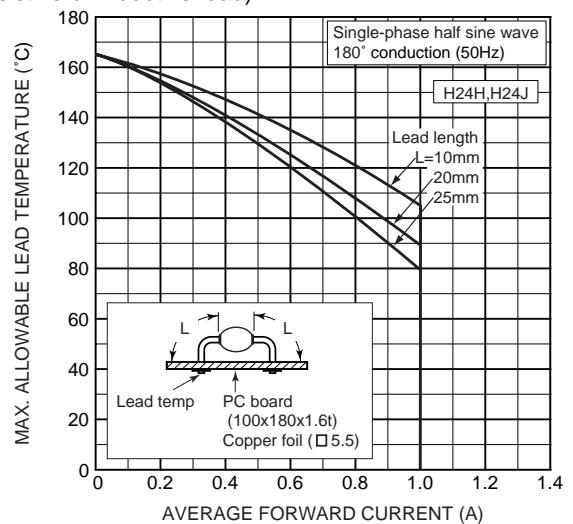
Max. allowable lead temperature (Resistive or inductive load)



Max. allowable ambient temperature (Resistive or inductive load)

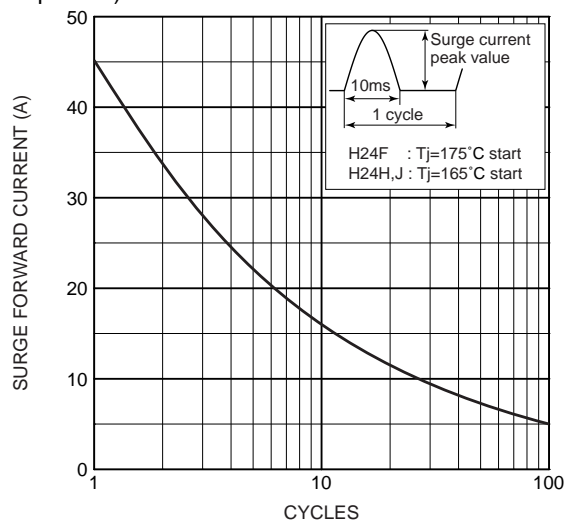


Max. allowable lead temperature (Resistive or inductive load)

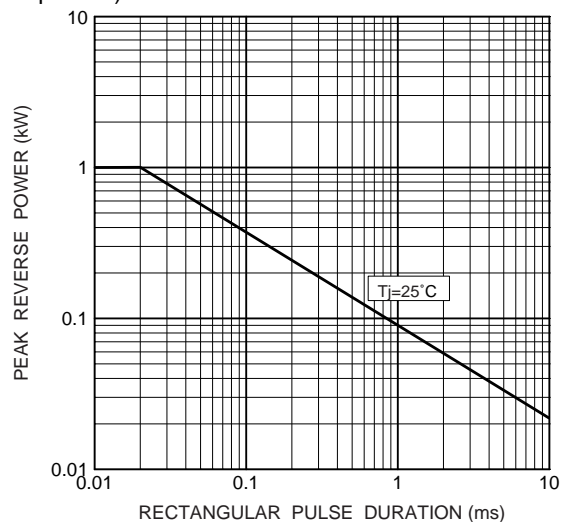


H24

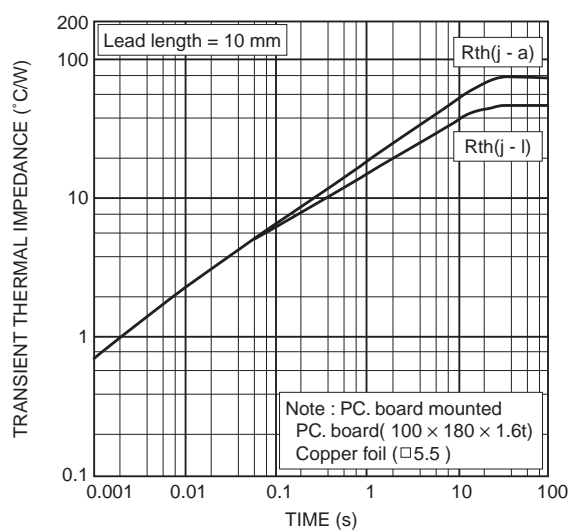
Surge forward current characteristics
(Non-repetitive)



Typical reverse power characteristics
(Non-repetitive)



Transient thermal impedance



HITACHI POWER SEMICONDUCTORS

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